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ON Semiconductor®

HUF76629D3ST-F085

N-Channel Logic Level UltraFET® Power MOSFET **100V**, **20A**, **52m** Ω

Features

- Typ $r_{DS(on)}$ = 41m Ω at V_{GS} = 10V, I_D = 20A
- Typ $Q_{g(tot)}$ = 39nC at V_{GS} = 10V, I_D = 20A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems



(TO-252)

MOSFET Maximum Ratings T_{.1} = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V_{DSS}	Drain to Source Voltage		100	V	
V_{GS}	Gate to Source Voltage		±16	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C = 25°C	20		
ID	Pulsed Drain Current	T _C = 25°C	See Figure4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	231	mJ	
P _D	Power Dissipation		150	W	
	Derate above 25°C		1	W/°C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance Junction to Case		1	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
HUF76629D3ST	HUF76629D3ST-F085	D-PAK(TO-252)	13"	12mm	2500 units

- 1: Current is limited by bondwire configuration.
- Starting T_J = 25°C, L = 1.8mH, I_{AS} = 16A, V_{DD} = 100V during inductor charging and V_{DD} = 0V during time in avalanche
 R_{0,JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Units

nΑ

Max

±100

Electrical Characteristics T_J = 25°C unless otherwise noted

Parameter

Gate to Source Leakage Current

Off Characteristics								
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_0$	_{GS} = 0V	100	-	-	V	
1	Drain to Source Leakage Current	V _{DS} =100V,	$T_{J} = 25^{\circ}C$	-	-	1	μΑ	
IDSS	Diam to Source Leakage Current	$V_{GS} = 0V$	$T_J = 175^{\circ}C(Note 4)$	-	-	1	mA	

 $V_{GS} = \pm 16V$

Test Conditions

Min

Тур

On Characteristics

Symbol

 I_{GSS}

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, I	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		1.6	3.0	V
r _{DS(on)}	Drain to Source On Resistance	$I_D = 20A$,	$T_{\rm J} = 25^{\rm o}{\rm C}$	-	41	52	mΩ
		V _{GS} = 10V	$T_J = 175^{\circ}C(Note 4)$	-	102	128	mΩ
		I _D = 20A,	$T_{\rm J} = 25^{\rm o}{\rm C}$		47	55	mΩ
		V_{GS} = 4.5 V	$T_J = 175^{\circ}C(Note 4)$		115	135	mΩ

Dynamic Characteristics

C _{iss}	Input Capacitance	-V _{DS} = 25V, V _{GS} = 0V, -f = 1MHz		-	1280	-	pF
C _{oss}	Output Capacitance			-	214	-	pF
C _{rss}	Reverse Transfer Capacitance			-	33	-	pF
R_g	Gate Resistance	f = 1MHz		-	2.5	-	Ω
$Q_{g(ToT)}$	Total Gate Charge	V _{GS} = 0 to 10V	V _{DD} = 50V	-	39	43	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to $2V$	I _D = 20A	-	2.3	3	nC
Q_{gs}	Gate to Source Gate Charge			1	3.5	1	nC
Q_{gd}	Gate to Drain "Miller" Charge			-	11	1	nC

Switching Characteristics

t _{on}	Turn-On Time		-	-	27	ns
$t_{d(on)}$	Turn-On Delay Time		-	7	-	ns
t _r	Rise Time	V _{DD} = 50V, I _D = 20A,	-	12	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{DD} = 50V, I_{D} = 20A, V_{GS} = 10V, R_{GEN} = 8.2 Ω	-	38	-	ns
t _f	Fall Time		-	5	-	ns
t _{off}	Turn-Off Time		-	-	47	ns

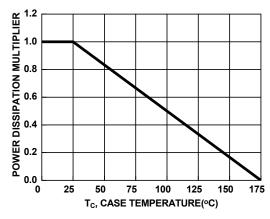
Drain-Source Diode Characteristics

V _{SD}	ISOURCE TO DRAIN DIOGE VOITAGE	I _{SD} = 20A, V _{GS} = 0V	-	-	1.25	V
		$I_{SD} = 10A, V_{GS} = 0V$	-	-	1.0	V
T _{rr}	Reverse Recovery Time	I _F = 20A, dI _{SD} /dt = 100A/μs,	-	77	99	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =80V	-	221	305	nC

Notes

4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.

Typical Characteristics



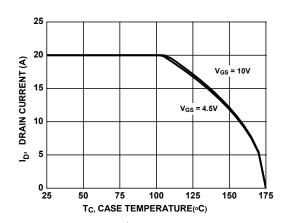


Figure 1. Normalized Power Dissipation vs Case Temperature

Figure 2. Maximum Continuous Drain Current vs Case Temperature

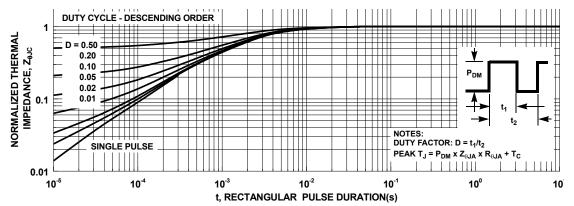


Figure 3. Normalized Maximum Transient Thermal Impedance

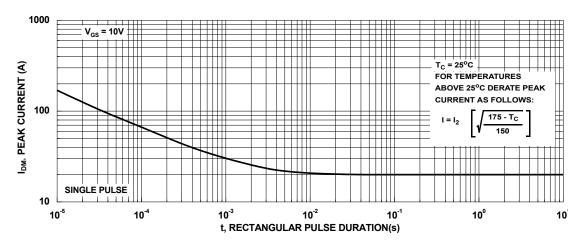
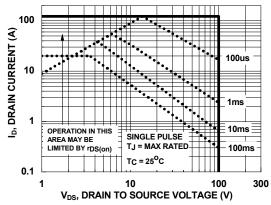


Figure 4. Peak Current Capability

Typical Characteristics



100

(Y)

If R = 0

If R = 0

If R ≠ 0

If R ≠ 0

If R ≠ 0

If R = 0

If R ≠ 0

If R = 0

If R ≠ 0

If R = 10

If R ≠ 0

If R ≠ 0

If R ≠ 0

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If R ≠ 0

If R = 0

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If R ≠ 0

If R = 0

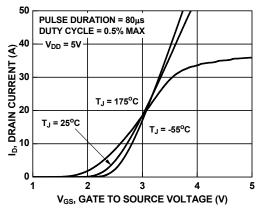
If R ≠ 0

If R

Figure 5. Forward Bias Safe Operating Area

NOTE: Refer to On Semiconductor Application Notes AN7514 and AN7515 $\,$

Figure 6. Unclamped Inductive Switching Capability



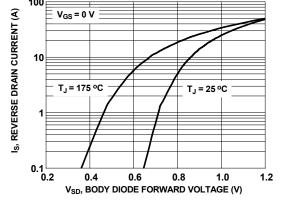
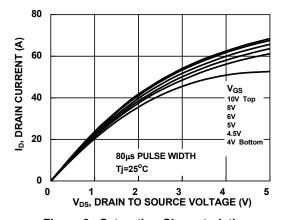


Figure 7. Transfer Characteristics

Figure 8. Forward Diode Characteristics



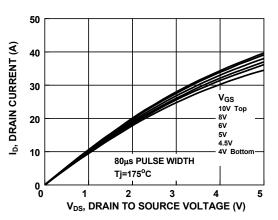


Figure 9. Saturation Characteristics

Figure 10. Saturation Characteristics

Typical Characteristics

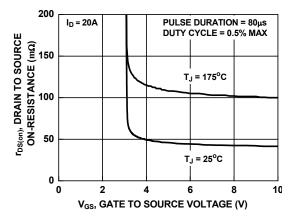


Figure 11. Rdson vs Gate Voltage

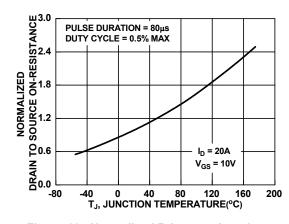


Figure 12. Normalized Rdson vs Junction Temperature

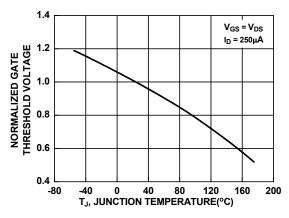


Figure 13. Normalized Gate Threshold Voltage vs
Temperature

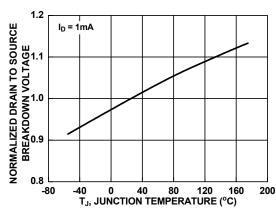


Figure 14. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

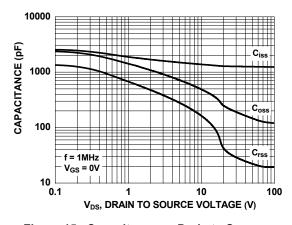


Figure 15. Capacitance vs Drain to Source Voltage

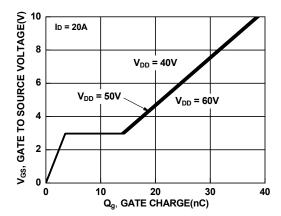


Figure 16. Gate Charge vs Gate to Source Voltage



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